## SIC SCHOTTKY DIODE TYPE 2×25A

Preliminary

### **Features**

- High surge current capable
- Zero reverse recovery current VDC
- · High bandwidth
- Isolation type package
- Temperature Independent Switching Behavior
- 1200 V
- **I**F (Tc<135°C) 2×25 A

## **Benefits**

- Unipolar rectifier
- Zero switching loss
- Smaller heat sink
- Parallel devices without thermal runaway
- Higher efficiency

# **Applications**

- Motor drives
- Switch mode power supplies
- Ev chargers
- Solar inverters
- Welding equipment
- Power factor correction
- Diode snubber
- Automotive
- · induction heating

# **Maximum Ratings**

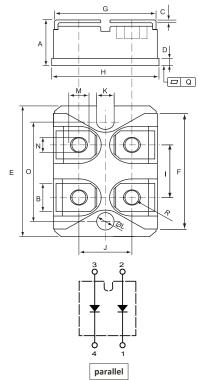
Operating Junction Temperature : - 55  $^{\circ}\mathrm{C}$  to +175  $^{\circ}\mathrm{C}$ 

Storage Temperature : -55  $^{\circ}$ C to +175  $^{\circ}$ C

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum DC Blocking Voltage
CSRI2×25-120P1B	1200V	1200V

Maximum Rating	Symbol	Conditions	Value	Unit	
Continuous forward current (per diode)	I <sub>F</sub>	T <sub>C</sub> =135 °C	25		
Surge non-repetitive forward current	I <sub>FSM</sub>	T <sub>C</sub> =25 °C, t <sub>p</sub> =8.3 ms	200		
sine halfwave (per diode)	. F2IM	$T_{C}$ =150 °C, $t_{p}$ =8.3 ms	125	Α	
Non-repetitive peak forward current	I <sub>F,max</sub>	$T_C$ =25 °C, $t_p$ =10 $\mu$ s	800		
(per diode)		$T_{C}$ =150 °C, $t_{p}$ =10 $\mu$ s	500		
Repetitive peak reverse voltage	$V_{RRM}$	T <sub>j</sub> =25 °C	1200	V	
Isolation voltage between All Terminals and Baseplate	V <sub>iso</sub>	50/60 Hz, t=1min I <sub>ISOL</sub> ≤ 1mA	2500	٧	
Mounting torque		To heatsink	1.3	Nm	
Intourising torque		To terminal	1.1	1 1 1 1 1 1	





DIMENSIONS					
	INCHES		M	M	
	MIN	MAX	MIN	MAX	
Α	0.460	0.483	11.68	12.28	
В	0.307	0.323	7.80	8.20	
С	0.030	0.033	0.75	0.85	
D	0.071	0.081	1.80	2.05	
E	1.488	1.504	37.80	38.20	
F	1.248	1.260	31.70	32.00	
G	0.917	0.957	23.30	24.30	
Н	0.996	1.008	25.30	25.60	
- 1	0.579	0.602	14.70	15.30	
J	0.492	0.516	12.50	13.10	
K	0.161	0.169	4.10	4.30	
L	0.161	0.169	4.10	4.30	
М	0.181	0.197	4.60	5.00	
N	0.165	0.181	4.20	4.60	
0	1.181	1.197	30.00	30.40	
Q	-0.002	0.004	-0.05	0.10	
R	M4*8				

# CSRI2×25-120P1B

### Electrical Characteristics, at T<sub>i</sub>=25 °C, unless otherwise specified. (per diode)

Static Characteristics	Symbol	Conditions	Values			
			min.	typ.	max.	Unit
DC blocking voltage	V <sub>DC</sub>		1,200	-	-	
Diode forward voltage	V <sub>F</sub>	I <sub>F</sub> =25A, T <sub>j</sub> =25 °C	-	1.6	1.8	V
		I <sub>F</sub> =25A, T <sub>j</sub> =175 °C	-	2.4	2.9	
	1-	V <sub>R</sub> =1,200V, T <sub>j</sub> =25 °C	-	20	50	
Reverse current	I <sub>R</sub>	V <sub>R</sub> =1,200V, T <sub>j</sub> =175 °C	-	50	200	$\mu A$

### AC Characteristics (per diode)

Static Characteristics	O make at	Conditions	Values			
	Symbol		min.	typ.	max.	Unit
Total capacitive charge	Q <sub>rr</sub>	V <sub>R</sub> =800V, T <sub>j</sub> =25 °C	-	53.34	-	nC
Total capacitance		V <sub>R</sub> =0V, f=1 MHz T <sub>j</sub> =25 °C	-	1,250	-	pF
	С	V <sub>R</sub> =400V, f=1 MHz T <sub>j</sub> =25 °C	-	122	-	
		V <sub>R</sub> =800V, f=1 MHz T <sub>i</sub> =25 °C	-	85	-	

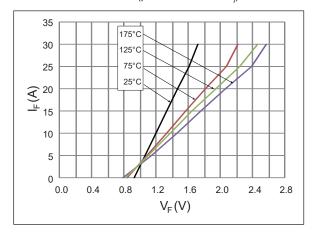
### Thermal Characteristics (per diode)

Statio Characteristics	Cumbal	Values		
Static Characteristics	Symbol	typ.	Unit	
Thermal resistance from junction to case	$R_{ heta  JC}$	0.56	°C/W	

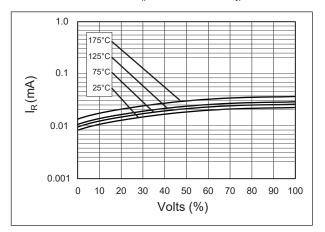
# CSRI2×25-120P1B

#### **Typical Performance**

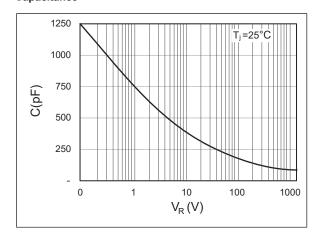
### Forward Characteristics (parameterized on T<sub>i</sub>)



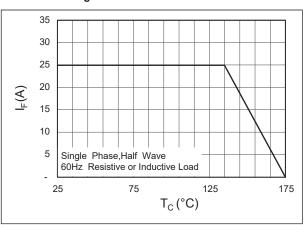
#### Reverse Characteristics (parameterized on Tj)



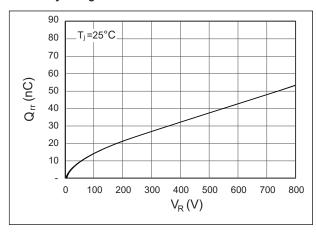
#### Capacitance



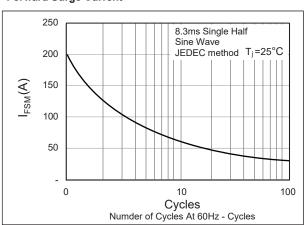
### **Current Derating**



### **Recovery Charge**



### **Forward Surge Current**



### CSRI2×25-120P1B

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